PTO/SB/08A (08-03)

Substitute for form 1449A/PTO

## INFORMATION DISCLOSURE STATEMENT BY APPLICANT

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Sheet 1 of 4	
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	Complete if Known
Application Number	10/773,796
Filing Date	February 6, 2004
First Named Inventor	Veerasamy, Vijayen
Art Unit	4773 176Z 11
Examiner Name	Unassigned Padgett
Attorney Docket Number	014089-002580US

		·	U.S. PATENT DO	CUMENTS+	
Examiner Initials	Cite No.	Document Number  Number Kind Code <sup>2</sup> (if known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
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	0009	US-5,091,049	02-25-1992	Campbell et al.	
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Examiner Signature	Mistalgett	Date Considered 2/8/05	

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Substitu	ute for form 1449A/P1	ro			Complete if Known
				Application Number	10/773,796
INF	ORMATION	I DI	SCLOSURE	Filing Date	February 6, 2004
STATEMENT BY APPLICANT				First Named Inventor	Veerasamy, Vijayen
				Art Unit	1773 1762
	(use as many sh	eets a	s necessary)	Examiner Name	Unassigned Padyett
Sheet	2	of	4	Attorney Docket Number	014089-002580US

				FOREIGN PA	TENT DOCUME	ENTS		
	I	F	oreign Patent Docu	ument /			Pages, Columns, Lines,	
	Cite No.1	Country Code <sup>3</sup>	Number <sup>4</sup>	Kirki Code* (# known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Where Relevant Passages or Relevant Figures Appear	T⁰
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Examiner Signature Date Considered 2/805

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INFO	DALATION	DIC	CL OCUDE	Application Number	10/773,796
	<del>-</del>		CLOSURE	Filing Date	February 6, 2004
STATEMENT BY APPLICANT				First Named Inventor	Veerasamy, Vijayen
				Art Unit	1773- 1762
(use as many sheets as necessary)		Examiner Name	Unassigned M.L. Padgett		
Sheet	3	of	4	Attorney Docket Number	014089-002580US

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		NON PATENT LITERATURE DOCUMENTS	1
Examiner Initials	Cite No.1	Include name of the duthor (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	
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	0046	Grill, A. et al.; "Diamondike Carbon Deposited by DC PACVIP," <u>Diamond Films and Techn.</u> ; 1992; pp. 219-233; vol. 1, No. 4.	
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	0054	Sager, O.; "The Influence of Nonuniform Density Distribution and Electron Temperature on the Helicon-Resonances in Low Pressure Discharges;" 1971.	

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INITOI	DRAKTION!	DIC	CLOCUDE	Application Number	10/773,796		
			CLOSURE	Filing Date	February 6, 2004		
STATEMENT BY APPLICANT			PPLICANT	First Named Inventor	Veerasamy, Vijayen		
				Art Unit	-1773-176Z		
(use as many sheets as necessary)		Examiner Name	Unassigned Padgett				
Sheet	4	of	4	Attorney Docket Number	014089-002580US		

		NON PATENT LITERATURE DOCUMENTS	
Examiner Initials *	Cite No.1	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or county where published.	T 2
	0055	Szuszczewicz, Edward P.; "Spatial Distributions of Plasma Density in a High-Frequency Discharge with a Superimposed Static Magnetic Field;" The Physics of Ekilds; 1972; pp. 2240-2246; vol. 15; No. 12.	
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Date Examiner Signature Considered

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